



SBR05U20LPS

0.5A SBR[®] SURFACE MOUNT SUPER BARRIER RECTIFIER

Product Summary (@ TA = +25°C)

V _{RRM} (V)	I _o (mA)	V _{F(MAX)} (V)	I _{R(MAX)} (μ A)
20	500	0.5	50

Features and Benefits

- Ultra Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Applications

- SMPS
- DC-DC Converter
- Freewheeling Diodes
- Reverse Polarity Protection

Mechanical Data

- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: Cathode Dot
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.001 grams (Approximate)

X2-DFN1006-3



Bottom View

Ordering Information (Note 4)

Part Number	Case	Packaging
SBR05U20LPS-7	X2-DFN1006-3	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

X2-DFN1006-3

• <u>5</u> 2

 $\frac{5}{2}$ = Product Type Marking Code Dot Denotes Cathode Side



Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	20	>
RMS Reverse Voltage	V _{R(RMS)}	14	V
Average Rectified Output Current (See Figure 1)	Ιο	500	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	6	А

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance (Note 5)	$R_{\theta JA}$	224	°C/W
Operating and Storage Temperature Range		-65 to +150	°C

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

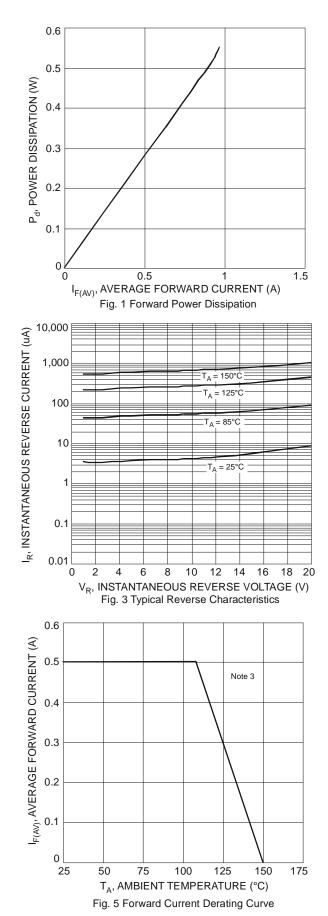
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V _{(BR)R}	20	-	-	V	I _R = 50μA
Forward Voltage Drop	VF	-	0.34 0.25 0.38 0.31 0.47 0.42	0.38 0.28 0.42 0.34 0.50 0.45	V	$\begin{split} I_F &= 0.1\text{A}, \ T_j = +25^{\circ}\text{C} \\ I_F &= 0.1\text{A}, \ T_j = +150^{\circ}\text{C} \\ I_F &= 0.2\text{A}, \ T_j = +25^{\circ}\text{C} \\ I_F &= 0.2\text{A}, \ T_j = +150^{\circ}\text{C} \\ I_F &= 0.5\text{A}, \ T_j = +25^{\circ}\text{C} \\ I_F &= 0.5\text{A}, \ T_j = +150^{\circ}\text{C} \end{split}$
Leakage Current (Note 6)	I _R	-	6 1.5	50 5	μA mA	$V_R = 20V, T_j = +25$ °C $V_R = 20V, T_j = +150$ °C

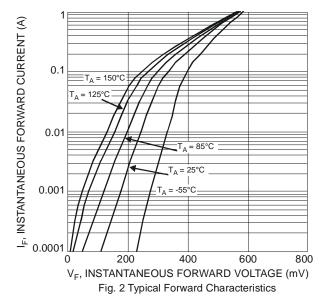
Notes:

^{5.} Device mounted on FR-4 substrate. 2" x 2" 2oz. Copper, single sided PCB board.

^{6.} Short duration pulse test used to minimize self-heating effect.







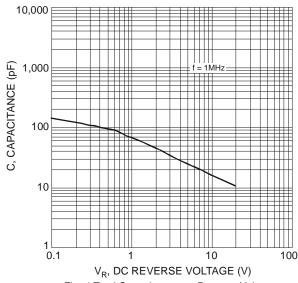
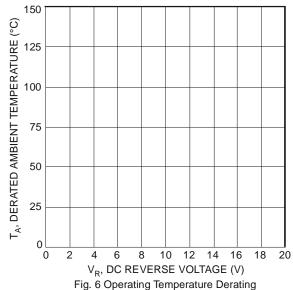


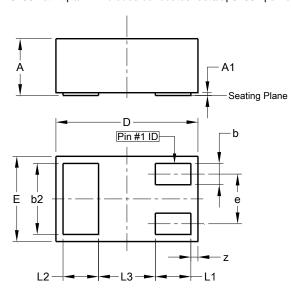
Fig. 4 Total Capacitance vs. Reverse Voltage





Package Outline Dimensions

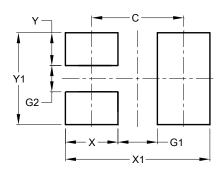
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X2-DFN1006-3				
Dim	Min	Max	Тур	
Α	_	0.40		
A1	0.00	0.05	0.03	
b	0.10	0.20	0.15	
b2	0.45	0.55	0.50	
ם	0.95	1.05	1.00	
Е	0.55	0.65	0.60	
е	1	1	0.35	
L1	0.20	0.30	0.25	
L2	0.20	0.30	0.25	
L3	-	-	0.40	
Z	0.02	0.08	0.05	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Y	0.25
Y1	0.70



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